DISCRETE SEMICONDUCTORS

DATA SHEET

PDTC143Z series NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Product data sheet Supersedes data of 2004 Apr 06 2004 Aug 16



NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | TYP. | MAX. | UNIT |
|-----------|---------------------------|------|------|------|
| V_{CEO} | collector-emitter voltage | _ | 50 | V |
| Io | output current (DC) | _ | 100 | mA |
| R1 | bias resistor | 4.7 | _ | kΩ |
| R2 | bias resistor | 47 | _ | kΩ |

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

| TYPE NUMBER | PAC | KAGE | MARKING CODE | PNP COMPLEMENT |
|-------------|---------------|--------------|--------------------|----------------|
| ITPE NUMBER | PHILIPS | PHILIPS EIAJ | | PNP COMPLEMENT |
| PDTC143ZE | SOT416 | SC-75 | 38 | PDTA143ZE |
| PDTC143ZEF | SOT490 | SC-89 | 53 | PDTA143ZEF |
| PDTC143ZK | SOT346 | SC-59 | 18 | PDTA143ZK |
| PDTC143ZM | SOT883 | SC-101 | E3 | PDTA143ZM |
| PDTC143ZS | SOT54 (TO-92) | SC-43 | TC143Z | PDTA143ZS |
| PDTC143ZT | SOT23 | _ | *18 ⁽¹⁾ | PDTA143ZT |
| PDTC143ZU | SOT323 | SC-70 | *54 ⁽¹⁾ | PDTA143ZU |

Note

^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

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PDTC143Z series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

| TYPE NUMBER | CIMPLIFIED OUTLINE AND CYMPOL | PINNING | | |
|--|--|---------|------------------------------|--|
| ITPE NUMBER | SIMPLIFIED OUTLINE AND SYMBOL | PIN | DESCRIPTION | |
| PDTC143ZS | | 1 | base | |
| | | 2 | collector | |
| | R1 R2 3 MAM364 | 3 | emitter | |
| PDTC143ZE PDTC143ZEF PDTC143ZK PDTC143ZT PDTC143ZU | Top view Top view Top view Top view | 1 2 3 | base emitter collector | |
| PDTC143ZM | 2 R1 R2 2 bottom view MHC506 | 1 2 3 | base emitter collector | |

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

ORDERING INFORMATION

| TYPE NUMBER | | PACKAGE | | | | |
|-------------|------|---|--------|--|--|--|
| ITPE NUMBER | NAME | DESCRIPTION | | | | |
| PDTC143ZE | _ | plastic surface mounted package; 3 leads | SOT416 | | | |
| PDTC143ZEF | - | plastic surface mounted package; 3 leads | SOT490 | | | |
| PDTC143ZK | _ | plastic surface mounted package; 3 leads | | | | |
| PDTC143ZM | _ | leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm | SOT883 | | | |
| PDTC143ZS | _ | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | | |
| PDTC143ZT | _ | plastic surface mounted package; 3 leads | SOT23 | | | |
| PDTC143ZU | _ | plastic surface mounted package; 3 leads | SOT323 | | | |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|--------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 50 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | 50 | V |
| V_{EBO} | emitter-base voltage | open collector | _ | 10 | V |
| VI | input voltage | | | | |
| | positive | | _ | +30 | V |
| | negative | | _ | -5 | V |
| Io | output current (DC) | | _ | 100 | mA |
| I _{CM} | peak collector current | | _ | 100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | |
| | SOT54 | note 1 | _ | 500 | mW |
| | SOT23 | note 1 | _ | 250 | mW |
| | SOT346 | note 1 | _ | 250 | mW |
| | SOT323 | note 1 | _ | 200 | mW |
| | SOT883 | notes 2 and 3 | _ | 250 | mW |
| | SOT416 | note 1 | _ | 150 | mW |
| | SOT490 | notes 1 and 2 | _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|---------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | |
| | SOT54 | note 1 | 250 | K/W |
| | SOT23 | note 1 | 500 | K/W |
| | SOT346 | note 1 | 500 | K/W |
| | SOT323 | note 1 | 625 | K/W |
| | SOT883 | notes 2 and 3 | 500 | K/W |
| | SOT416 | note 1 | 833 | K/W |
| | SOT490 | notes 1 and 2 | 500 | K/W |

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

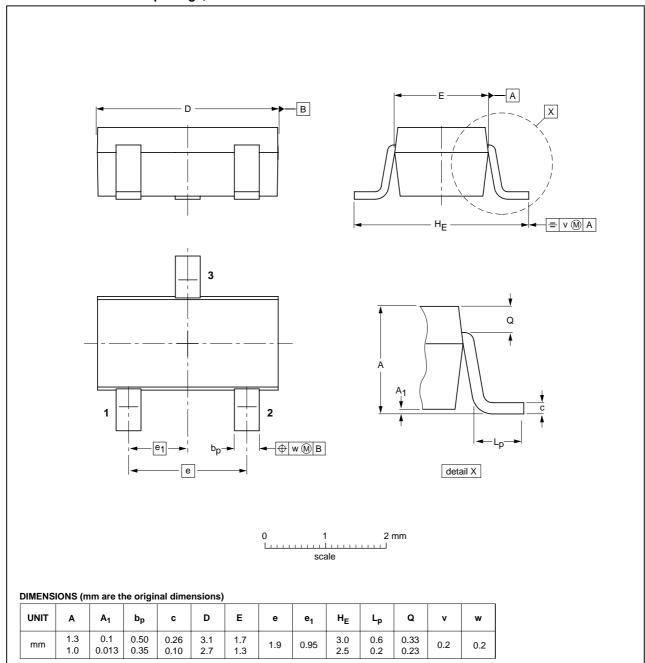
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|------|
| I _{CBO} | collector-base cut-off current | V _{CB} = 50 V; I _E = 0 A | _ | _ | 100 | nA |
| I _{CEO} | collector-emitter cut-off current | $V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$ | _ | _ | 1 | μΑ |
| | | $V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$ | _ | _ | 50 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 5 V; I _C = 0 A | _ | _ | 170 | μΑ |
| h _{FE} | DC current gain | $V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$ | 100 | _ | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$ | _ | _ | 100 | mV |
| $V_{i(off)}$ | input-off voltage | $I_C = 100 \mu A; V_{CE} = 5 V$ | _ | 0.6 | 0.5 | V |
| $V_{i(on)}$ | input-on voltage | $I_C = 5 \text{ mA}; V_{CE} = 0.3 \text{ V}$ | 1.3 | 0.9 | _ | V |
| R1 | input resistor | | 3.3 | 4.7 | 6.1 | kΩ |
| <u>R2</u> R1 | resistor ratio | | 8 | 10 | 12 | |
| C _c | collector capacitance | $I_E = I_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz | _ | _ | 2.5 | pF |

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

PACKAGE OUTLINES

Plastic surface-mounted package; 3 leads SOT346



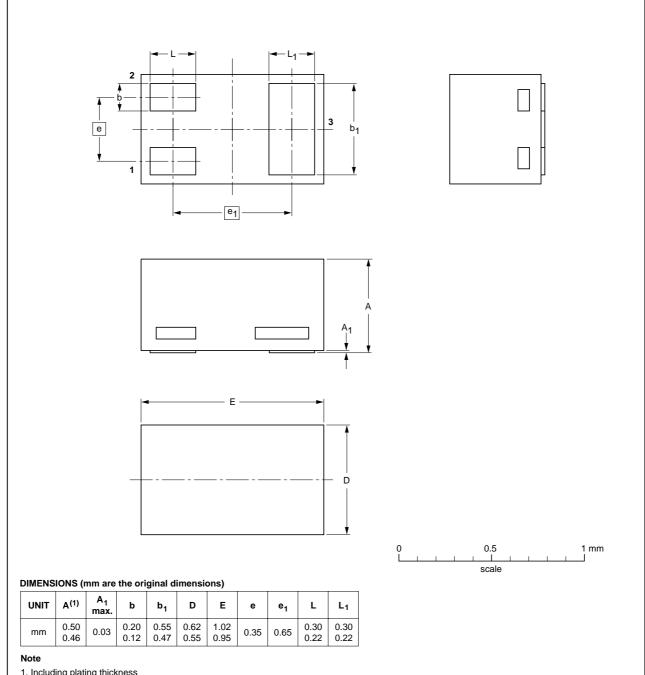
| OUTLINE | | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|-----|------------|--------|--|------------|----------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | |
| SOT346 | | TO-236 | SC-59A | | | -04-11-11 06-03-16 | |

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



1. Including plating thickness

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE | |
|---------|-----|-------|--------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | |
| SOT883 | | | SC-101 | | 03-02-05 03-04-03 | |

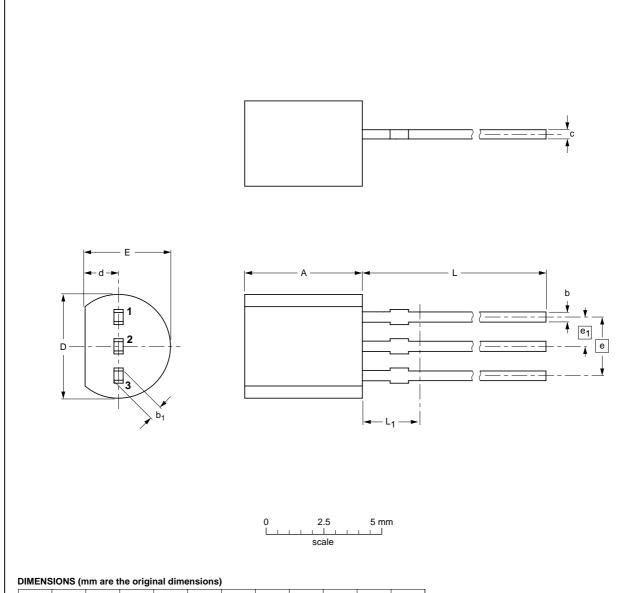
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NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



| UNIT | Α | b | b ₁ | С | D | d | E | е | e ₁ | L | L ₁ ⁽¹⁾ max. |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|---------------------------------------|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.55 | 0.45 0.38 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 |

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

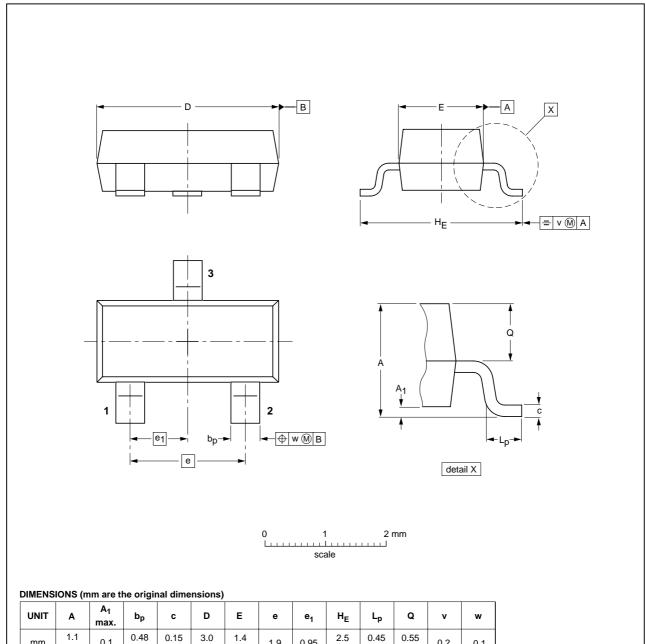
| OUTLINE | | REFER | RENCES | EUROPEAN | ISSUE DATE | |
|---------|-----|-------|--------|------------|-----------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | |
| SOT54 | | TO-92 | SC-43A | | -04-06-28- 04-11-16 | |

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT23



| OUTLINE | | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|-----|------------|-------|--|------------|-----------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | |
| SOT23 | | TO-236AB | | | | -04-11-04- 06-03-16 | |

0.2

0.1

1.9

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0.38

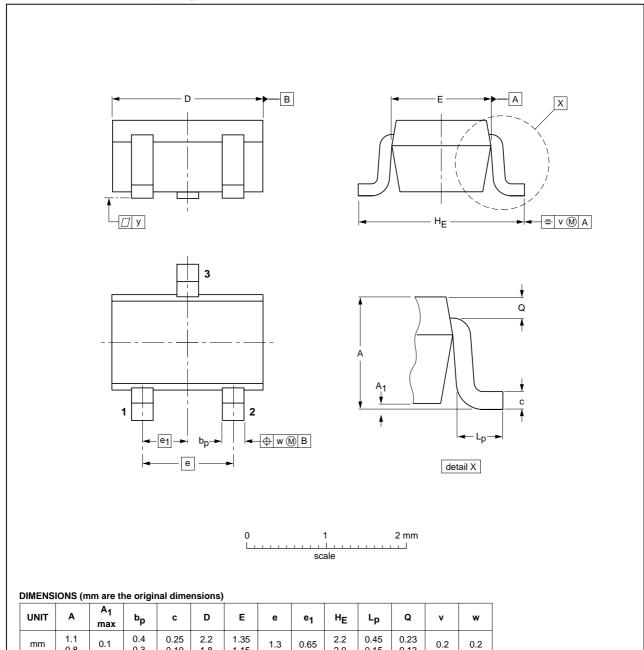
0.9

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT323



| OUTLINE | | REFER | RENCES | EUROPEAN | ISSUE DATE |
|---------|-----|-------|--------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT323 | | | SC-70 | | 04-11-04 06-03-16 |

10

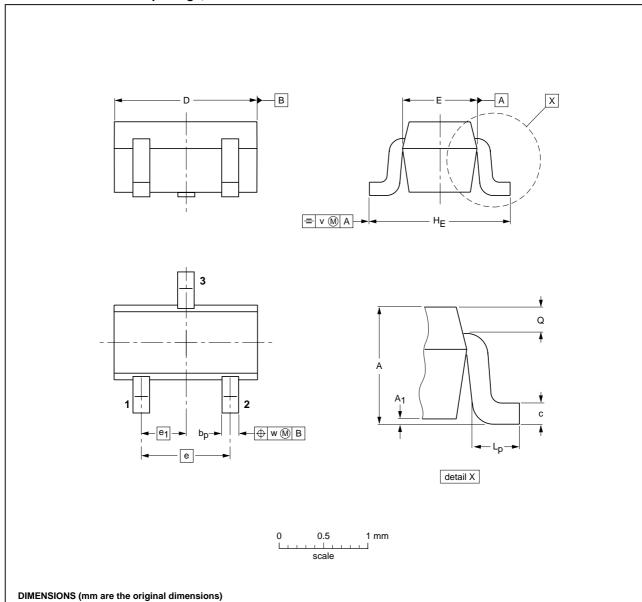
0.3

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT416



| UNIT | Α | A ₁ max | bp | С | D | E | е | e ₁ | HE | Lp | ø | v | w |
|------|--------------|-----------------------|--------------|--------------|------------|------------|---|----------------|--------------|--------------|--------------|-----|-----|
| mm | 0.95 0.60 | 0.1 | 0.30 0.15 | 0.25 0.10 | 1.8 1.4 | 0.9 0.7 | 1 | 0.5 | 1.75 1.45 | 0.45 0.15 | 0.23 0.13 | 0.2 | 0.2 |

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|---------|-----|-------|-------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT416 | | | SC-75 | | 04-11-04 06-03-16 |

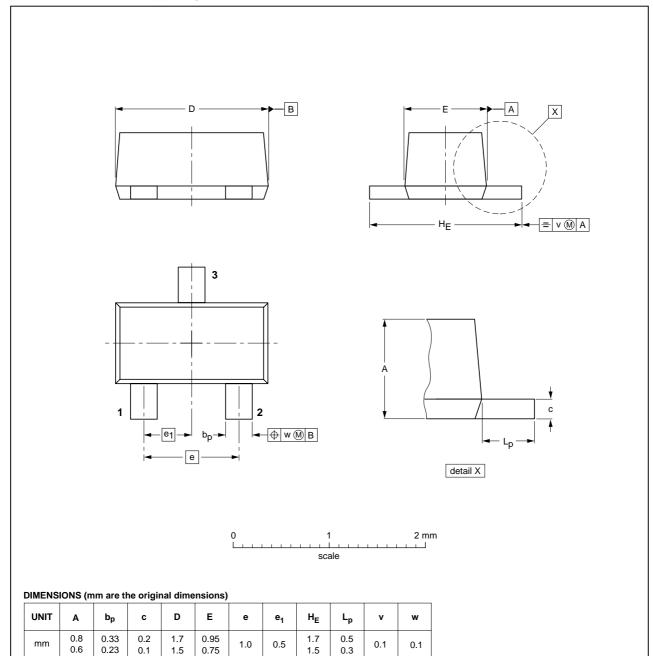
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NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT490



| VERSION IEC JEDEC JEITA PROJECTION 95-07 | OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|--|---------|-----|-------|-------|--------------|---------------------------------|
| | VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| 30-09 06-03 | SOT490 | | | SC-89 | | 05-07-28 06-03-16 |

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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Contact information

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